Dual 4-channel analog multiplexer/demultiplexer

Rev. 1 — 12 July 2012

Product data sheet

1. General description

The HEF4052B-Q100 is a dual 4-channel analog multiplexer/demultiplexer with common channel select logic. Each multiplexer/demultiplexer has four independent inputs/outputs (nY0 to nY3) and a common input/output (nZ). The common channel select logic includes two select inputs (S1 and S2) and an active LOW enable input (\overline{E}). Both multiplexers/demultiplexers contain four bidirectional analog switches, each with one side connected to an independent input/output (nY0 to nY3) and the other side connected to a common input/output (nZ). With \overline{E} LOW, one of the four switches is selected (low-impedance ON-state) by S1 and S2. With \overline{E} HIGH, all switches are in the high-impedance OFF-state, independent of S1 and S2. If break before make is needed, then it is necessary to use the enable input.

 V_{DD} and V_{SS} are the supply voltage connections for the digital control inputs (S1 and S2, and \overline{E}). The V_{DD} to V_{SS} range is 3 V to 15 V. The analog inputs/outputs (nY0 to nY3, and nZ) can swing between V_{DD} as a positive limit and V_{EE} as a negative limit. $V_{DD} - V_{EE}$ may not exceed 15 V. Unused inputs must be connected to V_{DD} , V_{SS} , or another input. For operation as a digital multiplexer/demultiplexer, V_{EE} is connected to V_{SS} (typically ground). V_{EE} and V_{SS} are the supply voltage connections for the switches.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- ESD protection:
 - MIL-STD-833, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Complies with JEDEC standard JESD 13-B

3. Applications

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



Dual 4-channel analog multiplexer/demultiplexer

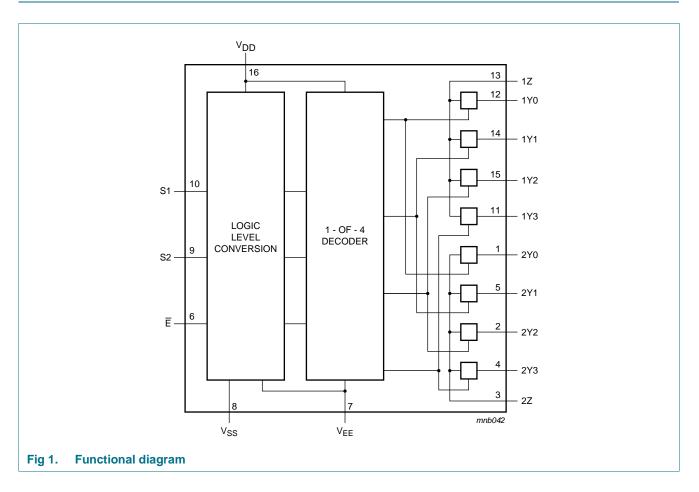
4. Ordering information

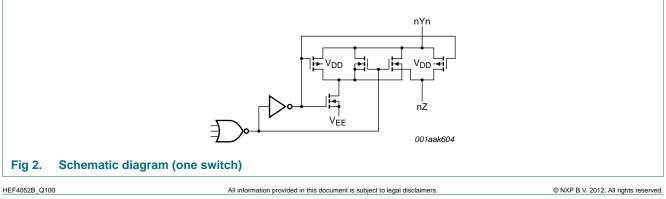
Table 1. Ordering information

All types operate from -40 °C to +125 °C.

| Type number | Package | kage | | | | | | |
|-----------------|---------|--|----------|--|--|--|--|--|
| | Name | Description | Version | | | | | |
| HEF4052BT-Q100 | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 | | | | | |
| HEF4052BTT-Q100 | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 | | | | | |

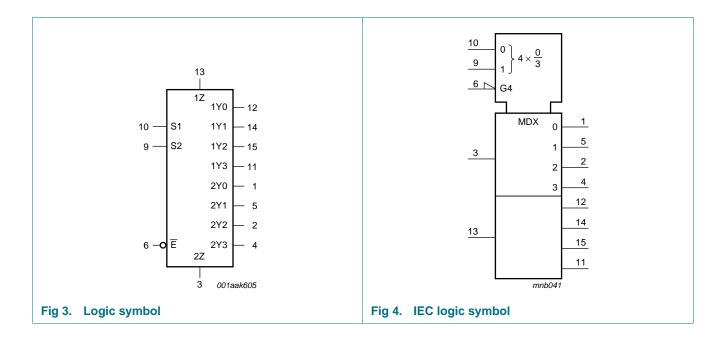
5. Functional diagram





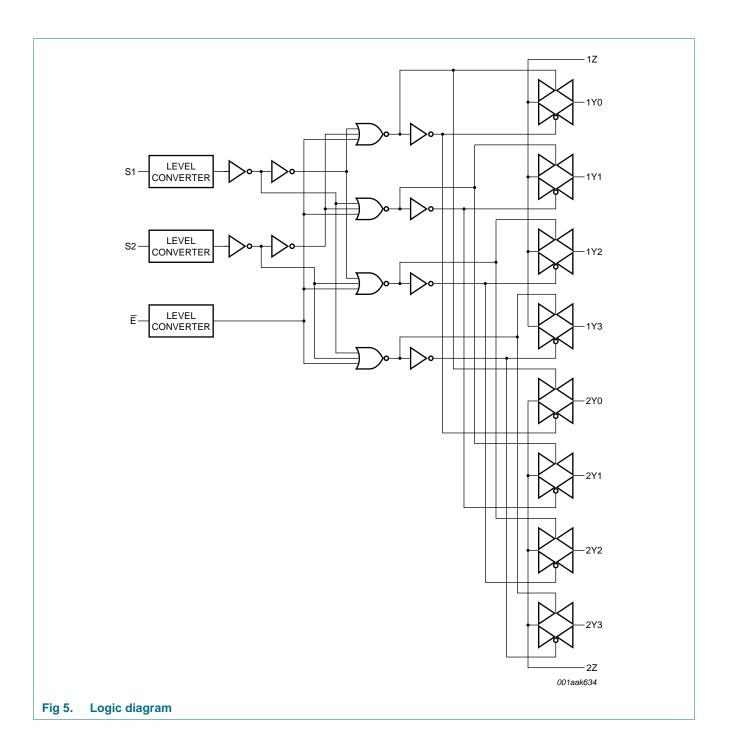
HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer



HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer

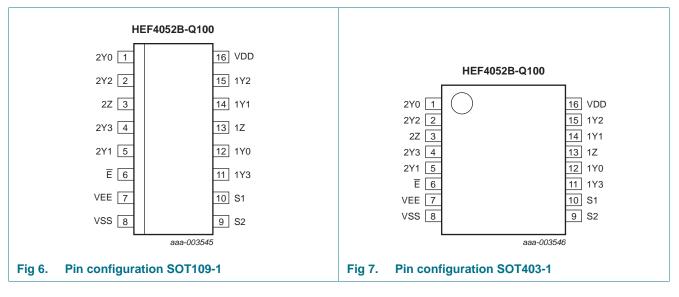


HEF4052B_Q100 Product data sheet

Dual 4-channel analog multiplexer/demultiplexer

6. Pinning information

6.1 Pinning



6.2 Pin description

. ..

| Table 2. | Pin description | | |
|-----------------|-----------------------------|----------------------------|-----------------------------|
| Symbol | | Pin | Description |
| Ē | | 6 | enable input (active LOW) |
| V_{EE} | | 7 | supply voltage |
| V _{SS} | | 8 | ground supply voltage |
| S1, S2 | | 10, 9 | select input |
| 1Y0, 1Y1, 1 | Y2, 1Y3, 2Y0, 2Y1, 2Y2, 2Y3 | 12, 14, 15, 11, 1, 5, 2, 4 | independent input or output |
| 1Z, 2Z | | 13, 3 | common output or input |
| V _{DD} | | 16 | supply voltage |
| | | | |

Dual 4-channel analog multiplexer/demultiplexer

7. Functional description

7.1 Function table

| Table 3. | Function table ^[1] | | | |
|----------|-------------------------------|----|--------------|--|
| Input | | | Channel on | |
| E | S2 | S1 | | |
| L | L | L | nY0 to nZ | |
| L | L | Н | nY1 to nZ | |
| L | Н | L | nY2 to nZ | |
| L | Н | Н | nY3 to nZ | |
| Н | Х | Х | switches off | |

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

8. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 V$ (ground).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|----------------|-----------------------|------|
| V _{DD} | supply voltage | | -0.5 | +18 | V |
| V _{EE} | supply voltage | referenced to V _{DD} | <u>[1]</u> –18 | +0.5 | V |
| Ι _{ΙΚ} | input clamping current | pins Sn and $\overline{E};$ V _I < –0.5 V or V _I > V _{DD} + 0.5 V | - | ±10 | mA |
| VI | input voltage | | -0.5 | V _{DD} + 0.5 | V |
| I _{I/O} | input/output current | | - | ±10 | mA |
| I _{DD} | supply current | | - | 50 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$ | | | |
| | | SO16 and TSSOP16 package | <u>[1]</u> - | 500 | mW |
| Р | power dissipation | per output | - | 100 | mW |

[1] To avoid drawing V_{DD} current out of terminal Z, when switch current flows into terminals Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no V_{DD} current will flow out of terminals Y, and in this case there is no limit for the voltage drop across the switch, but the voltages at Y and Z may not exceed V_{DD} or V_{EE} .

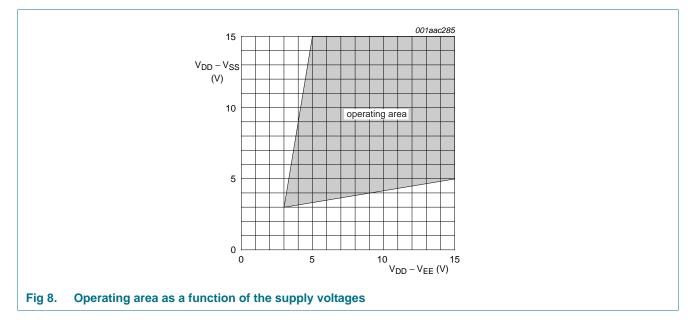
For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 $^\circ\text{C}.$

For TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

Dual 4-channel analog multiplexer/demultiplexer

9. Recommended operating conditions

| . Recommended operating conditions | | | | | | | |
|------------------------------------|---|--|---|---|---|--|--|
| Parameter | Conditions | Min | Тур | Max | Unit | | |
| supply voltage | see Figure 8 | 3 | - | 15 | V | | |
| input voltage | | 0 | - | V_{DD} | V | | |
| ambient temperature | in free air | -40 | - | +125 | °C | | |
| input transition rise and fall | $V_{DD} = 5 V$ | - | - | 3.75 | μs/V | | |
| rate | V _{DD} = 10 V | - | - | 0.5 | μs/V | | |
| | $V_{DD} = 15 V$ | - | - | 0.08 | μs/V | | |
| | Parameter supply voltage input voltage ambient temperature input transition rise and fall | ParameterConditionssupply voltagesee Figure 8input voltageinput voltageambient temperaturein free airinput transition rise and fall rate $V_{DD} = 5 V$ $V_{DD} = 10 V$ | ParameterConditionsMinsupply voltagesee Figure 83input voltage0ambient temperaturein free air-40input transition rise and fall rate $V_{DD} = 5 V$ - $V_{DD} = 10 V$ - | ParameterConditionsMinTypsupply voltagesee Figure 83-input voltage0-ambient temperaturein free air-40-input transition rise and fall rate $V_{DD} = 5 V$ $V_{DD} = 10 V$ | ParameterConditionsMinTypMaxsupply voltagesee Figure 83-15input voltage0- V_{DD} ambient temperaturein free air-40-+125input transition rise and fall rate $V_{DD} = 5 V$ 3.75 $V_{DD} = 10 V$ 0.5 | | |



10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = V_{EE} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

| Symbol | Parameter | Conditions | V _{DD} | T _{amb} = | –40 °C | T _{amb} = | ≥ 25 °C | T _{amb} = | 85 °C | T _{amb} = 125 °C | | Unit |
|-----------------|--------------------------|-----------------------------|-----------------|--------------------|--------|--------------------|---------|--------------------|-------|---------------------------|------|------|
| | | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| V _{IH} | IH HIGH-level | $ I_0 < 1 \ \mu A$ | 5 V | 3.5 | - | 3.5 | - | 3.5 | - | 3.5 | - | V |
| | input voltage | | 10 V | 7.0 | - | 7.0 | - | 7.0 | - | 7.0 | - | V |
| | | | 15 V | 11.0 | - | 11.0 | - | 11.0 | - | 11.0 | - | V |
| V _{IL} | LOW-level | el I _O < 1 μA | 5 V | - | 1.5 | - | 1.5 | - | 1.5 | - | 1.5 | V |
| | input voltage | | 10 V | - | 3.0 | - | 3.0 | - | 3.0 | - | 3.0 | V |
| | | | 15 V | - | 4.0 | - | 4.0 | - | 4.0 | - | 4.0 | V |
| I | input leakage current | | 15 V | - | ±0.1 | - | ±0.1 | - | ±1.0 | - | ±1.0 | μΑ |

HEF4052B_Q100
Product data sheet

Dual 4-channel analog multiplexer/demultiplexer

Table 6. Static characteristics ...continued

 $V_{SS} = V_{EE} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

| Symbol | Parameter | Conditions | V _{DD} | T _{amb} = | –40 °C | T _{amb} = | = 25 °C | T _{amb} = | : 85 °C | T _{amb} = 125 °C | | Unit |
|---------------------|---------------------------------|---|-----------------|--------------------|--------|--------------------|---------|--------------------|---------|---------------------------|-----|------|
| | | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| I _{S(OFF)} | OFF-state leakage current | Z port; all channels OFF; see <u>Figure 9</u> | 15 V | - | - | - | 1000 | - | - | - | - | nA |
| | | Y port; per channel; see <u>Figure 10</u> | 15 V | - | - | - | 200 | - | - | - | - | nA |
| I _{DD} | supply current | I _O = 0 A | 5 V | - | 5 | - | 5 | - | 150 | - | 150 | μA |
| | | | 10 V | - | 10 | - | 10 | - | 300 | - | 300 | μA |
| | | | 15 V | - | 20 | - | 20 | - | 600 | - | 600 | μA |
| CI | input capacitance | Sn, \overline{E} inputs | - | - | - | - | 7.5 | - | - | - | - | pF |

10.1 Test circuits

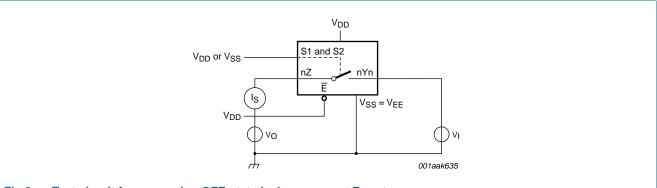
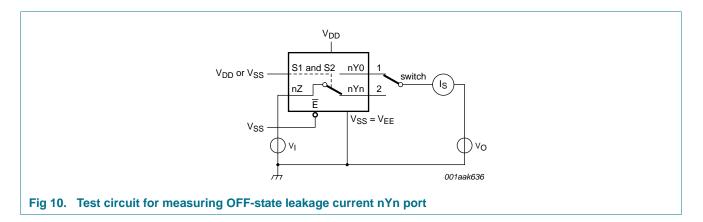


Fig 9. Test circuit for measuring OFF-state leakage current Z port



Dual 4-channel analog multiplexer/demultiplexer

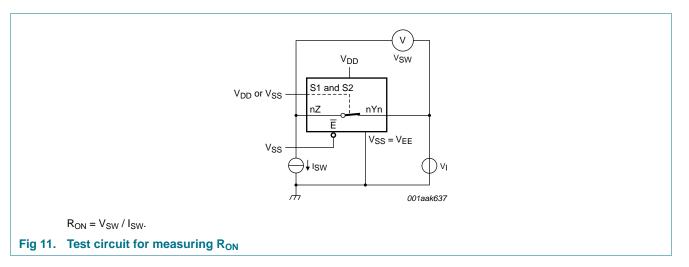
10.2 On resistance

Table 7. ON resistance

 $T_{amb} = 25 \ ^{\circ}C; I_{SW} = 200 \ \mu A; V_{SS} = V_{EE} = 0 \ V.$

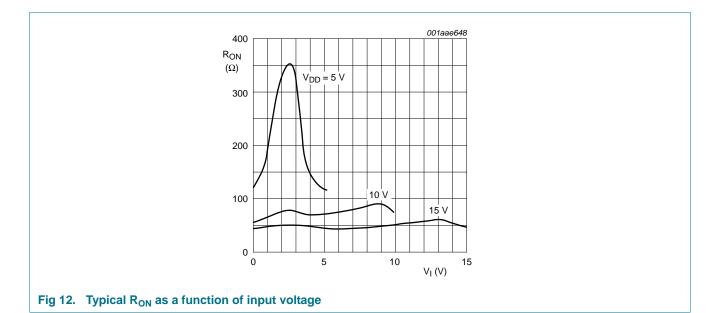
| Symbol | Parameter | Conditions | $V_{DD} - V_{EE}$ | Тур | Max | Unit |
|-----------------------|------------------------|--|-------------------|-----|------|------|
| R _{ON(peak)} | ON resistance (peak) | $V_I = 0 V \text{ to } V_{DD} - V_{EE};$ | 5 V | 350 | 2500 | Ω |
| | | see Figure 11 and Figure 12 | 10 V | 80 | 245 | Ω |
| | | | 15 V | 60 | 175 | Ω |
| R _{ON(rail)} | ON resistance (rail) | $V_I = 0 V$; see Figure 11 and Figure 12 | 5 V | 115 | 340 | Ω |
| | | | 10 V | 50 | 160 | Ω |
| | | | 15 V | 40 | 115 | Ω |
| | | $V_I = V_{DD} - V_{EE};$ | 5 V | 120 | 365 | Ω |
| | | see Figure 11 and Figure 12 | 10 V | 65 | 200 | Ω |
| | | | 15 V | 50 | 155 | Ω |
| ΔR_{ON} | ON resistance mismatch | $V_I = 0 V$ to $V_{DD} - V_{EE}$; see Figure 11 | 5 V | 25 | - | Ω |
| | between channels | | 10 V | 10 | - | Ω |
| | | | 15 V | 5 | - | Ω |
| | | | | | | |

10.2.1 On resistance waveform and test circuit



HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer



11. Dynamic characteristics

Table 8. Dynamic characteristics

 $T_{amb} = 25 \ ^{\circ}C$; $V_{SS} = V_{EE} = 0 \ V$; for test circuit see Figure 16.

| Symbol | Parameter | Conditions | V _{DD} | Тур | Max | Unit |
|------------------|-------------------------------|------------------------------------|-----------------|-----|-----|------|
| PHL | HIGH to LOW propagation delay | nYn, nZ to nZ, nYn; see Figure 13 | 5 V | 10 | 20 | ns |
| | | | 10 V | 5 | 10 | ns |
| | | | 15 V | 5 | 10 | ns |
| | | Sn to nYn, nZ; see Figure 14 | 5 V | 150 | 305 | ns |
| | | | 10 V | 65 | 135 | ns |
| | | | 15 V | 50 | 100 | ns |
| t _{PLH} | LOW to HIGH propagation delay | Yn, nZ to nZ, nYn; see Figure 13 | 5 V | 10 | 20 | ns |
| | | | 10 V | 5 | 10 | ns |
| | | | 15 V | 5 | 10 | ns |
| | | Sn to nYn, nZ; see Figure 14 | 5 V | 150 | 300 | ns |
| | | | 10 V | 75 | 150 | ns |
| | | | 15 V | 50 | 100 | ns |
| t _{PHZ} | HIGH to OFF-state | E to nYn, nZ; see <u>Figure 15</u> | 5 V | 95 | 190 | ns |
| | propagation delay | | 10 V | 90 | 180 | ns |
| | | | 15 V | 85 | 180 | ns |
| t _{PZH} | OFF-state to HIGH | E to nYn, nZ; see Figure 15 | 5 V | 130 | 260 | ns |
| | propagation delay | | 10 V | 55 | 115 | ns |
| | | | 15 V | 45 | 85 | ns |
| t _{PLZ} | LOW to OFF-state | E to nYn, nZ; see Figure 15 | 5 V | 100 | 205 | ns |
| | propagation delay | | 10 V | 90 | 180 | ns |
| | | | 15 V | 90 | 180 | ns |

Dual 4-channel analog multiplexer/demultiplexer

| $T_{amb} = 25$ | $T_{amb} = 25 \ ^{\circ}C; V_{SS} = V_{EE} = 0 \ V; for test circuit see Figure 16.$ | | | | | | | | | | |
|----------------|--|-----------------------------|-----------------|-----|-----|------|--|--|--|--|--|
| Symbol | Parameter | Conditions | V _{DD} | Тур | Max | Unit | | | | | |
| | OFF-state to LOW | E to nYn, nZ; see Figure 15 | 5 V | 120 | 240 | ns | | | | | |
| | propagation delay | | 10 V | 50 | 100 | ns | | | | | |
| | | | 15 V | 35 | 75 | ns | | | | | |

Table 8. Dynamic characteristics ...continued

11.1 Waveforms and test circuit

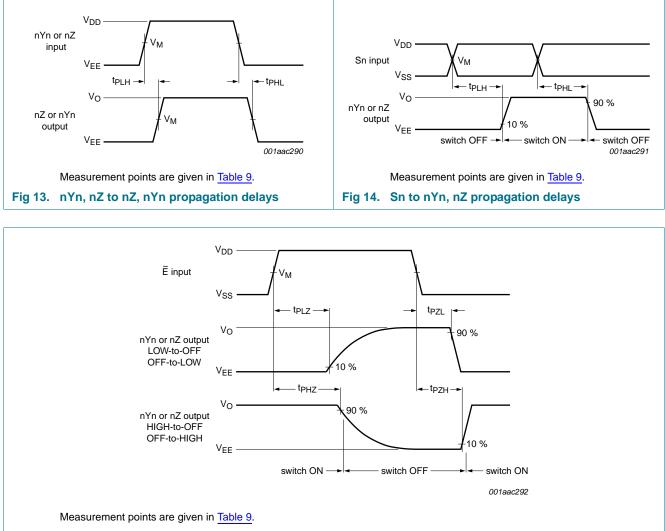


Fig 15. Enable and disable times

Table 9. Measurement points

| Supply voltage | Input | Output |
|-----------------|--------------------|--------------------|
| V _{DD} | V _M | V _M |
| 5 V to 15 V | 0.5V _{DD} | 0.5V _{DD} |

Dual 4-channel analog multiplexer/demultiplexer

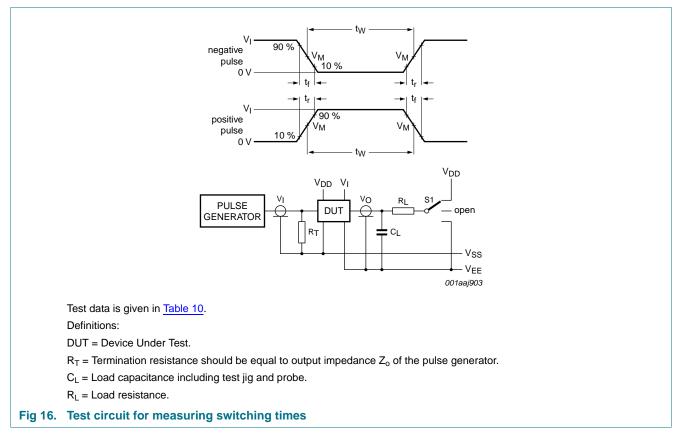


Table 10. Test data

| Input | | | Load | Load S1 position | | | | | | |
|---|-----------------------|---------------------------------|--------------------|------------------|-------|----------------------|------------------|-------------------------------------|-------------------------------------|-----------------|
| nYn, nZ | Sn and \overline{E} | t _r , t _f | V _M | CL | RL | t _{PHL} [1] | t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | other |
| $V_{\text{DD}} \text{ or } V_{\text{EE}}$ | V_{DD} or V_{SS} | ≤ 20 ns | 0.5V _{DD} | 50 pF | 10 kΩ | V_{DD} or V_{EE} | V _{EE} | V _{EE} | V _{DD} | V _{EE} |

[1] For nYn to nZ propagation delays use V_{EE} . For Sn to nYn or nZ propagation delays use V_{DD} .

Dual 4-channel analog multiplexer/demultiplexer

11.2 Additional dynamic parameters

Table 11. Additional dynamic characteristics

 $V_{\text{SS}} = V_{EE} = 0$ V; $T_{amb} = 25$ °C.

| Symbol | Parameter | Conditions | V _{DD} | Тур | Max | Unit |
|---------------------|---------------------------|---|-----------------|-----------------------|-----|------|
| THD | total harmonic distortion | see Figure 17; $R_L = 10 \text{ k}\Omega$; $C_L = 15 \text{ pF}$; channel ON; $V_I = 0.5V_{DD}$ (p-p); $f_i = 1 \text{ kHz}$ | 5 V | <mark>[1]</mark> 0.25 | - | % |
| | | | 10 V | <u>[1]</u> 0.04 | - | % |
| | | | 15 V | <u>[1]</u> 0.04 | - | % |
| f _(-3dB) | –3 dB frequency response | see Figure 18; $R_L = 1 \text{ k}\Omega$; $C_L = 5 \text{ pF}$; channel ON; $V_I = 0.5V_{DD}$ (p-p) | 5 V | [<u>1]</u> 13 | - | MHz |
| | | | 10 V | <u>[1]</u> 40 | - | MHz |
| | | | 15 V | [<u>1]</u> 70 | - | MHz |
| α_{iso} | isolation (OFF-state) | see Figure 19; $f_i = 1 \text{ MHz}$; $R_L = 1 \text{ k}\Omega$; $C_L = 5 \text{ pF}$; channel OFF; $V_I = 0.5V_{DD}$ (p-p) | 10 V | <u>[1]</u> –50 | - | dB |
| V _{ct} | crosstalk voltage | digital inputs to switch; see Figure 20; $\underline{R}_{L} = 10 \text{ k}\Omega$; $C_{L} = 15 \text{ pF}$; $\overline{E} \text{ or Sn} = V_{DD}$ (square-wave) | 10 V | 50 | - | mV |
| Xtalk | crosstalk | between switches; see <u>Figure 21</u> ; $f_i = 1 \text{ MHz}; R_L = 1 \text{ k}\Omega;$ $V_I = 0.5V_{DD} \text{ (p-p)}$ | 10 V | <u>[1]</u> –50 | - | dB |

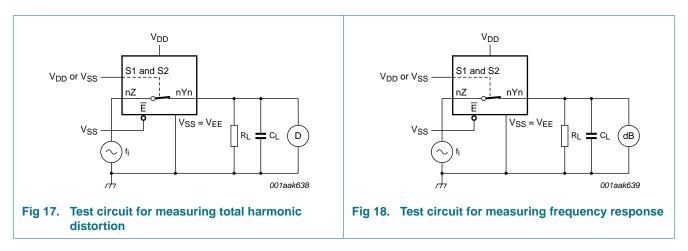
[1] f_i is biased at 0.5 V_{DD}; V_I = 0.5V_{DD} (p-p).

Table 12. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown; $V_{EE} = V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

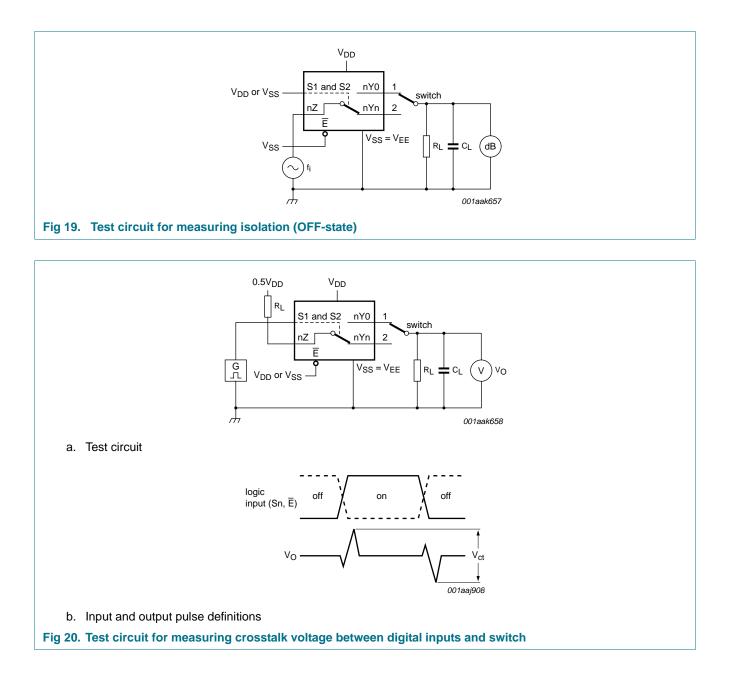
| Symbol | Parameter | V _{DD} | Typical formula for P_D (μ W) | where: |
|----------------|------------------------------|-----------------|--|--|
| P _D | dynamic power dissipation | 5 V | $P_D = 1300 \times f_i + \Sigma (f_o \times C_L) \times V_DD^2$ | f_i = input frequency in MHz; |
| | | 10 V | $P_D = 6100 \times f_i + \Sigma (f_o \times C_L) \times V_DD^2$ | $f_o = output frequency in MHz;$ |
| | | 15 V | $P_{D} = 15600 \times f_{i} + \Sigma (f_{o} \times C_{L}) \times V_{DD}^{2}$ | C_L = output load capacitance in pF; |
| | | | | V _{DD} = supply voltage in V; |
| | | | | $\Sigma(C_L \times f_o)$ = sum of the outputs. |

11.2.1 Test circuits



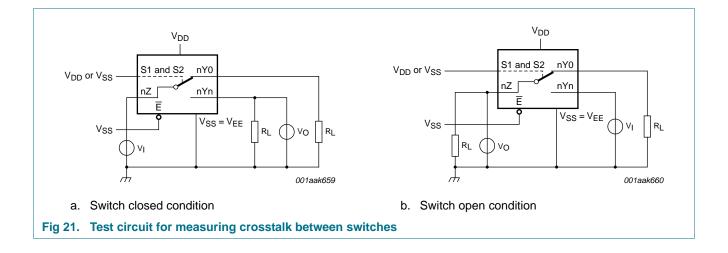
HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer



HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer



HEF4052B-Q100

Dual 4-channel analog multiplexer/demultiplexer

12. Package outline

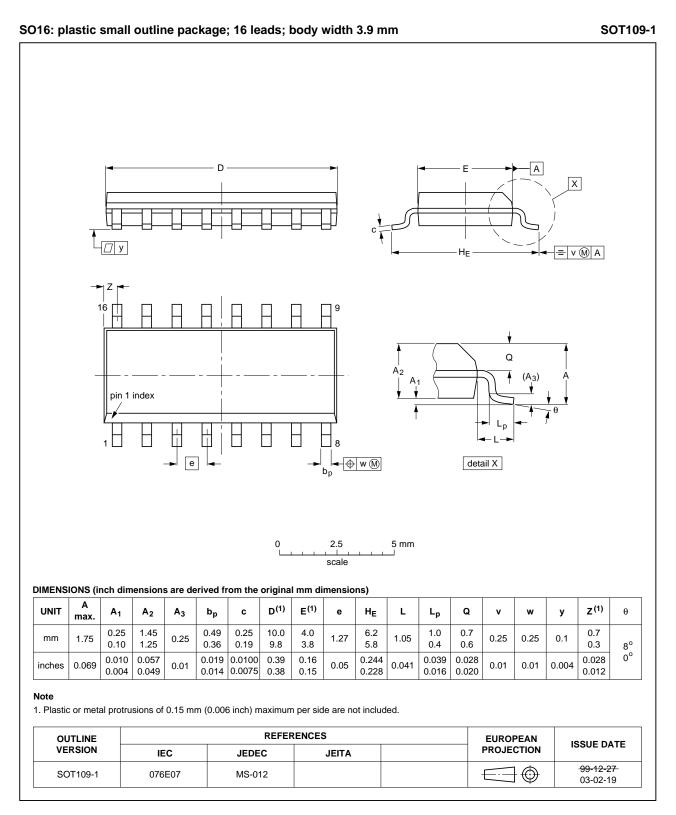


Fig 22. Package outline SOT109-1 (SO16)

All information provided in this document is subject to legal disclaimers.

HEF4052B_Q100

Dual 4-channel analog multiplexer/demultiplexer

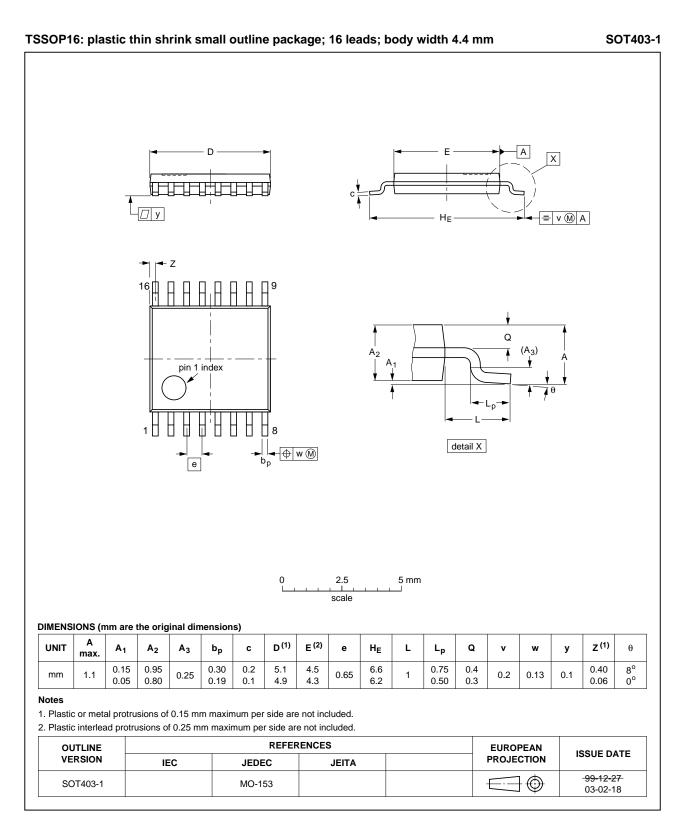


Fig 23. Package outline SOT403-1 (TSSOP16)

All information provided in this document is subject to legal disclaimers.

HEF4052B_Q100

Dual 4-channel analog multiplexer/demultiplexer

13. Abbreviations

| Table 13. Abbreviations | | | | |
|-------------------------|-------------------------|--|--|--|
| Acronym | Description | | | |
| HBM | Human Body Model | | | |
| ESD | ElectroStatic Discharge | | | |
| MM | Machine Model | | | |
| MIL | Military | | | |

14. Revision history

| Table 14. Revision history | | | | | |
|----------------------------|--------------|--------------------|---------------|------------|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
| HEF4052B_Q100_1 | 20120712 | Product data sheet | - | - | |

Dual 4-channel analog multiplexer/demultiplexer

15. Legal information

15.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

15.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

15.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications - This NXP

Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

Dual 4-channel analog multiplexer/demultiplexer

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

15.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

16. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

Dual 4-channel analog multiplexer/demultiplexer

17. Contents

| 1 | General description | . 1 |
|--------|---|-----|
| 2 | Features and benefits | . 1 |
| 3 | Applications | . 1 |
| 4 | Ordering information | 2 |
| 5 | Functional diagram | . 2 |
| 6 | Pinning information | 5 |
| 6.1 | Pinning | . 5 |
| 6.2 | Pin description | 5 |
| 7 | Functional description | 6 |
| 7.1 | Function table | . 6 |
| 8 | Limiting values | 6 |
| 9 | Recommended operating conditions | . 7 |
| 10 | Static characteristics | . 7 |
| 10.1 | Test circuits | . 8 |
| 10.2 | On resistance | 9 |
| 10.2.1 | On resistance waveform and test circuit | . 9 |
| 11 | Dynamic characteristics | 10 |
| 11.1 | Waveforms and test circuit | 11 |
| 11.2 | Additional dynamic parameters | 13 |
| 11.2.1 | Test circuits | 13 |
| 12 | Package outline | 16 |
| 13 | Abbreviations | 18 |
| 14 | Revision history | 18 |
| 15 | Legal information | 19 |
| 15.1 | Data sheet status | 19 |
| 15.2 | Definitions | 19 |
| 15.3 | Disclaimers | 19 |
| 15.4 | Trademarks | 20 |
| 16 | Contact information | |
| 17 | Contents | 21 |

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2012.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 12 July 2012 Document identifier: HEF4052B_Q100